

SBR3M30P1

3.0A SBR[®] SURFACE MOUNT SUPER BARRIER RECTIFIER POWERDI[®]123

Features

- Ultra Low Leakage Current
- Excellent High Temperature Stability
- Superior Reverse Avalanche Capability
- Patented Interlocking Clip Design for High Surge Current Capacity
- Patented Super Barrier Rectifier Technology
- · Soft, Fast Switching Capability
- 175°C Operating Junction Temperature
- ±16KV ESD Protection (HBM, 3B)
- ±25KV ESD Protection (IEC61000-4-2 Level 4, Air Discharge)
- Lead Free Finish, RoHS Compliant (Note 1)
- "Green" Molding Compound (No Br, Sb)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: POWERDI[®]123
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Polarity Indicator: Cathode Band
- Terminals: Matte Tin Finish annealed over Copper leadframe.
 Solderable per MIL-STD-202, Method 208 63
- Weight: 0.018 grams (approximate)

POWERDI®123



Top View

Ordering Information (Note 2)

Part Number	Case	Packaging
SBR3M30P1-7	POWERDI [®] 123	3000/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2). All applicable RoHS exemptions applied
- 2. For packaging details, go to our website at http://www.diodes.com.

Marking Information



3M3 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: T = 2006) M = Month (ex: 9 = September)

Date Code Key

Year	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015	2016	2017
Code	Т	J	V	W	Χ	Υ	Z	Α	В	С	D	Е
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings @T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	V _{RRM} V _{RWM}	30	V
DC Blocking Voltage	VRW	00	v
RMS Reverse Voltage	V _{R(RMS)}	21	V
Average Rectified Output Current (See Figure 1)	lo	3.0	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	75	А
Non-Repetitive Avalanche Energy (Per Element) (T _J = 25°C, I _{AS} = 5A, L = 8.5mH)	E _{AS}	105	mJ
Repetitive Peak Avalanche Energy (Per Element) (1µs, 25°C)	P _{ARM}	1100	W

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance Thermal Resistance Junction to Soldering (Note 3) Thermal Resistance Junction to Ambient (Note 4) Thermal Resistance Junction to Ambient (Note 5)	R _θ JS R _θ JA R _θ JA	5 183 125	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +175	°C

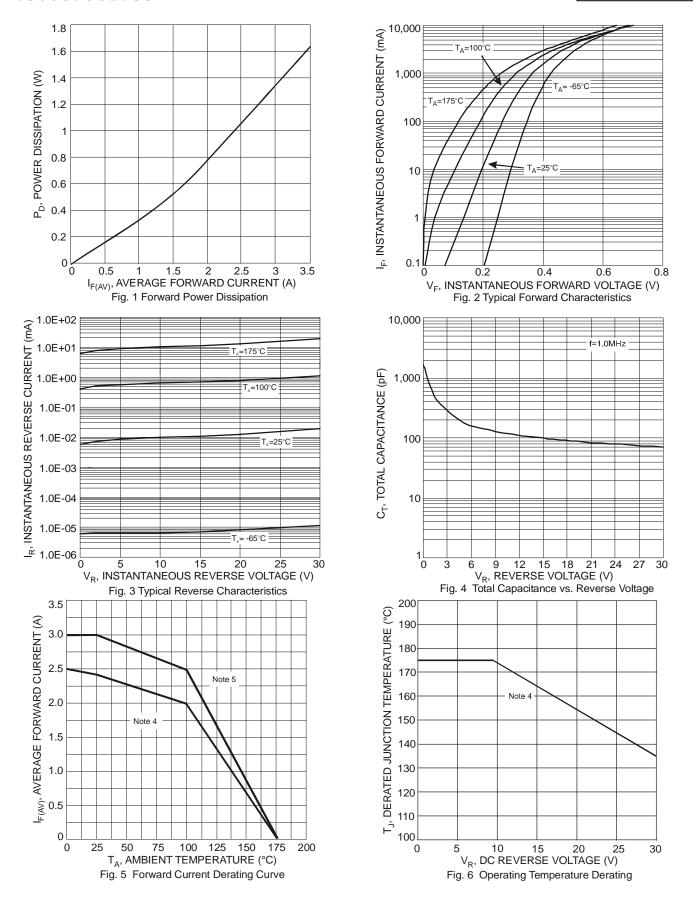
Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 6)	$V_{(BR)R}$	30	-	-	V	$I_R = 250\mu A$
Forward Voltage Drop	V _F		0.26 0.37 0.46 0.16 0.29 0.42	0.30 0.41 0.50 0.19 0.32 0.45	V	$\begin{split} I_F &= 0.1 \text{A}, \ T_J = 25^{\circ}\text{C} \\ I_F &= 1.0 \text{A}, \ T_J = 25^{\circ}\text{C} \\ I_F &= 3.0 \text{A}, \ T_J = 25^{\circ}\text{C} \\ I_F &= 0.1 \text{A}, \ T_J = 125^{\circ}\text{C} \\ I_F &= 1.0 \text{A}, \ T_J = 125^{\circ}\text{C} \\ I_F &= 3.0 \text{A}, \ T_J = 125^{\circ}\text{C} \\ \end{split}$
Leakage Current (Note 6)	I _R	-	8.5 19 1.7 3.1	100 200 15 20	μΑ μΑ mA mA	$\begin{split} &V_R = 5V, T_J = 25^{\circ}C \\ &V_R = 30V, T_J = 25^{\circ}C \\ &V_R = 5V, T_J = 125^{\circ}C \\ &V_R = 30V, T_J = 125^{\circ}C \end{split}$

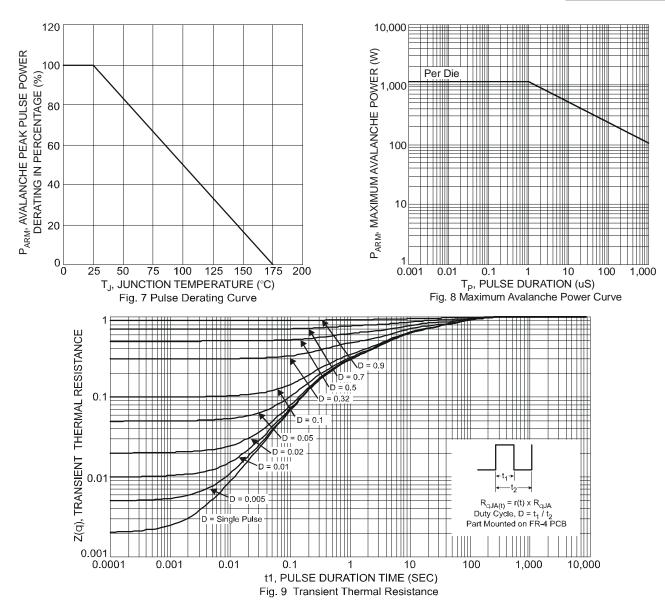
Notes:

- 3. Theoretical R_{eJS} calculated from the top center of the die straight down to the PCB cathode tab solder junction. 4. FR-4 PCB, 2 oz. Copper, minimum recommended pad layout per http://www.diodes.com.
- 5. Polymide PCB, 2 oz. Copper, minimum recommended pad layout per http://www.diodes.com. 6. Short duration pulse test used to minimize self-heating effect.

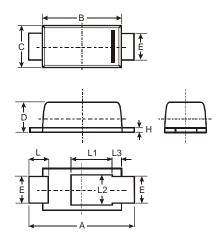








Package Outline Dimensions

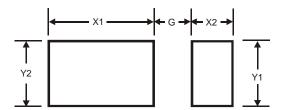


POWERDI [®] 123								
Dim	Min	Max	Тур					
Α	3.50	3.90	3.70					
В	2.60	3.00	2.80					
U	1.63	1.93	1.78					
ם	0.93	1.00	0.98					
ш	0.85	1.25	1.00					
Н	0.15	0.25	0.20					
J	0.40	0.50	0.45					
L1	-	-	1.35					
L2	-	-	1.10					
L3	-	-	0.20					
All Dimensions in mm								

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Suggested Pad Layout



Dimensions	Value (in mm)
G	1.0
X1	2.2
X2	0.9
Y1	1.4
Y2	1.4

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